

RoHS

COMPLIANT

GREEN (5-2008)\*\*

# High Speed Infrared Emitting Diodes, 850 nm, Surface Emitter Technology



#### DESCRIPTION

VSMY2850 series are infrared, 850 nm emitting diodes based on GaAlAs surface emitter chip technology with extreme high radiant intensities, high optical power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

#### **APPLICATIONS**

- IrDA compatible data transmission
- Miniature light barrier
- Photointerrupters
- · Optical switch
- Emitter source for proximity sensors
- IR touch panels
- IR illumination

#### **FEATURES**

Package type: surface mountPackage form: GW, RGW

• Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8

Peak wavelength: λ<sub>p</sub> = 850 nm

· High reliability

High radiant power

Very high radiant intensity

• Angle of half intensity:  $\varphi = \pm 10^{\circ}$ 

• Suitable for high pulse current operation

Terminal configurations: gullwing or reverse gullwing

Package matches with detector VEMD2500X01 series

• Floor life: 4 weeks, MSL 2a, acc. J-STD-020

 Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

• Halogen-free according to IEC 61249-2-21 definition

#### Note

\*\* Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

PRODUCT SUMMARY				
COMPONENT	I <sub>e</sub> (mW/sr)	φ (deg)	λ <sub>P</sub> (nm)	t <sub>r</sub> (ns)
VSMY2850RG	100	± 10	850	10
VSMY2850G	100	± 10	850	10

#### Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMY2850RG	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMY2850G	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

#### Note

MOQ: minimum order quantity



<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		$V_R$	5	V
Forward current		I <sub>F</sub>	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I <sub>FM</sub>	200	mA
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	А
Power dissipation		P <sub>V</sub>	190	mW
Junction temperature		T <sub>j</sub>	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 85	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature	acc. figure 7, J-STD-020	T <sub>sd</sub>	260	°C
Thermal resistance junction/ambient	J-STD-051, soldered on PCB	R <sub>thJA</sub>	250	K/W

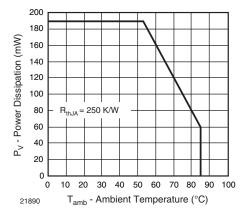


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

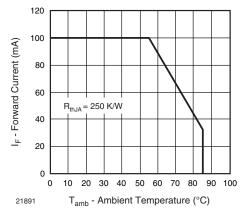


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Farmer described	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>		1.65	1.9	V
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \ \mu\text{s}$	V <sub>F</sub>		2.9		V
Tanana and an ana filiation of the	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>		- 1.45		mV/K
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 10 mA	TK <sub>VF</sub>		- 1.3		mV/K
Reverse current		I <sub>R</sub>	not desigr	ned for reverse	operation	μΑ
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ		125		pF
De Paris Internal	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	50	100	150	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	l <sub>e</sub>		850		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe		55		mW
Temperature coefficient of radiant power	I <sub>F</sub> = 100 mA	TΚφ <sub>e</sub>		- 0.35		%/K
Angle of half intensity		φ		± 10		deg
Peak wavelength	I <sub>F</sub> = 100 mA	λρ	840	850	870	nm
Spectral bandwidth	I <sub>F</sub> = 30 mA	Δλ		30		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 30 mA	TKλ <sub>p</sub>		0.25		nm/K
Rise time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>r</sub>		10		ns
Fall time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>f</sub>		10		ns
Virtual source diameter		d		1.5		mm

#### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

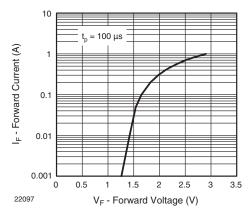


Fig. 3 - Forward Current vs. Forward Voltage

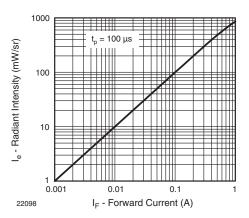


Fig. 4 - Radiant Intensity vs. Forward Current

## $\lambda$ - Wavelength (nm) Fig. 5 - Relative Radiant Power vs. Wavelength 0° 10° 20° 30° I ee - Relative Radiant Intensity φ - Angular Displacemen 40° 1.0 0.9 609 0.8

850

950

70° 80°

750

Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

0.2 0

#### **SOLDER PROFILE**

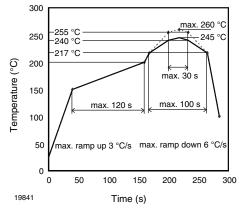


Fig. 7 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

#### **DRYPACK**

21111

0.7

0.6 0.4

rel - Relative Radiant Power

 $\Phi_{\rm e}$ 

0.75

0.5

0.25

650

 $I_{E} = 30 \text{ mA}$ 

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

Conditions:  $T_{amb}$  < 30 °C, RH < 60 %

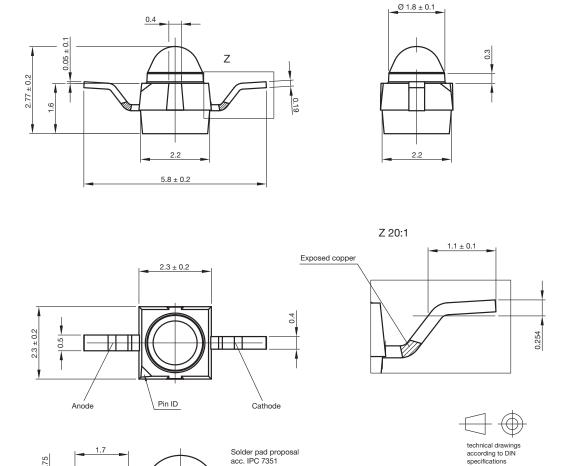
Moisture sensitivity level 2a, acc. to J-STD-020.

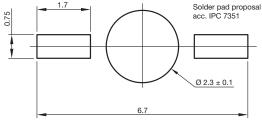
#### **DRYING**

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

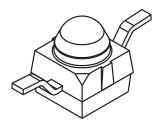


#### PACKAGE DIMENSIONS in millimeters: VSMY2850RG





Not indicated tolerances  $\pm$  0.1

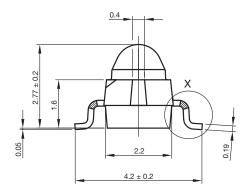


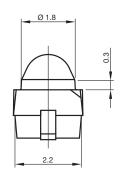
Drawing-No.: 6.544-5391.03-4

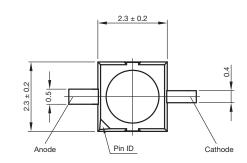
Issue: 1; 18.03.10

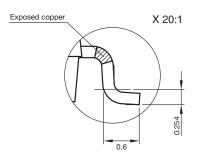
22100

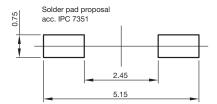
#### PACKAGE DIMENSIONS in millimeters: VSMY2850G











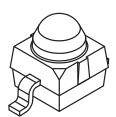


Drawing-No.: 6.544-5383.03-4

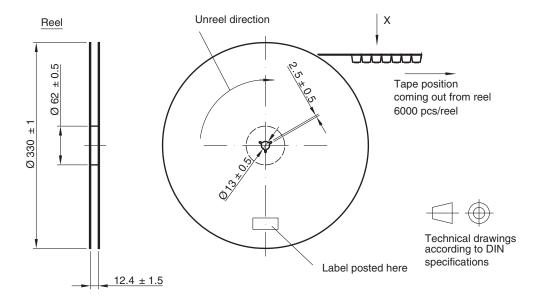
Issue: 1; 18.03.10

22099

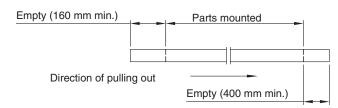
Not indicated tolerances ± 0.1



#### TAPING AND REEL DIMENSIONS in millimeters: VSMY2850RG

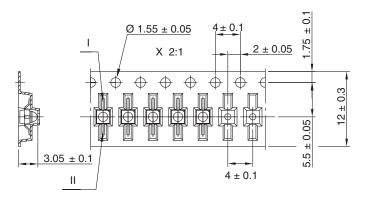


Leader and trailer tape:



#### Terminal position in tape

Devicce	Lead I	Lead II
VEMT2000		
VEMT2500	Collector	Emitter
VEMD2000		
VEMD2500	0-4	Anode
VSMB2000	Cathode	Anode
VSMG2000		
VSMY2850RG	Anode	Cathode

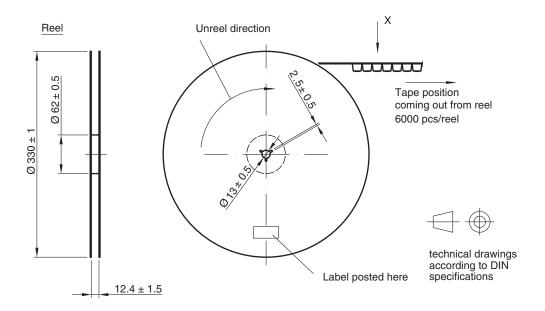


Drawing-No.: 9.800-5100.01-4

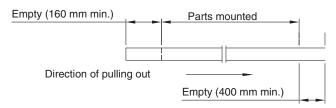
Issue: 2; 18.03.10

21572

#### TAPING AND REEL DIMENSIONS in millimeters: VSMY2850G

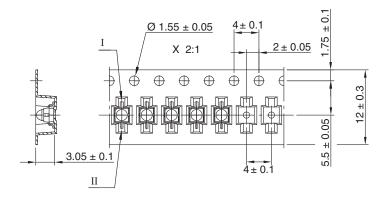


#### Leader and trailer tape:



#### Terminal position in tape

Devicce	Lead I	Lead II
VEMT2020		
VEMT2520	Collector	Emitter
VSMB2020		
VSMG2020	Cathada	Anada
VEMD2020	Cathode	Anode
VEMD2520		
VSMY2850G	Anode	Cathode



Drawing-No.: 9.800-5091.01-4

Issue: 3; 18.03.10

21571





Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 11-Mar-11